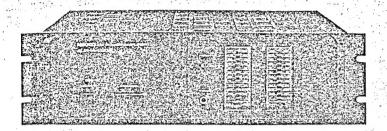
NIIKKO POWER AMP





TYPE AND VOLTAGE

W-TYPE:	UL and CSA type	120V AC
E -TYPE:	NK-STD type	220V AC
B -TYPE:	BS type	240V AC

SERVICE MANUAL

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SPECIFICATIONS

AMPLIFIER SECTION	
Continuous Power Output per Channel: 20 ~ 20000 Hz (8 ohms) more than 120 Watts 20 ~ 20000 Hz (4 ohms) more than 130 Watts 1000 Hz (8 ohms) more than 120 Watts 1000 Hz (4 ohms) more than 130 Watts	Frequency Response, "NORMAL" input, 8 ohms: at 1 Watt power Output 10 ~ 100000Hz +0, -1dB Input Sensitivity for 120 Watts Power Output: MAIN IN 1V ± 2dB Signal to Noise Ratio, IHF "A" Network:
T. H. Distortion, 8 ohms: at Continuous Power Output no more than 0.008% at 1 Watt Power Output no more than 0.02% T. H. Distortion, 4 ohms: at Continuous Power Output no more than 0.02% I. M. Distortion, 8 ohms: at Continuous Power Output no more than 0.01% at 1 Watt Power Output no more than 0.02% IHF Power Bandwidth, 8 ohms: 5 ~ 70000Hz Damping Factor at 1000 Hz, 8 ohms: more than 60	MAIN (NORMAL, DIRECT) better than 105dB Signal to Noise Ratio, DIN Filter: MAIN IN (NORMAL, DIRECT) better than 90dB Channel Balance: no more than 1dB Residual Hum and Noise, 8 ohms: no more than 0.5mV Idling Current: 40 ~ 120mA Midpoint Voltage: 0 ± 20mV Muting Delay Time: 3 ~ 7 seconds
GENERAL	
Power Requirement: W-TYPE	Dimensions: Width

Weight, without package: 13.5 kg (29.7 lbs)

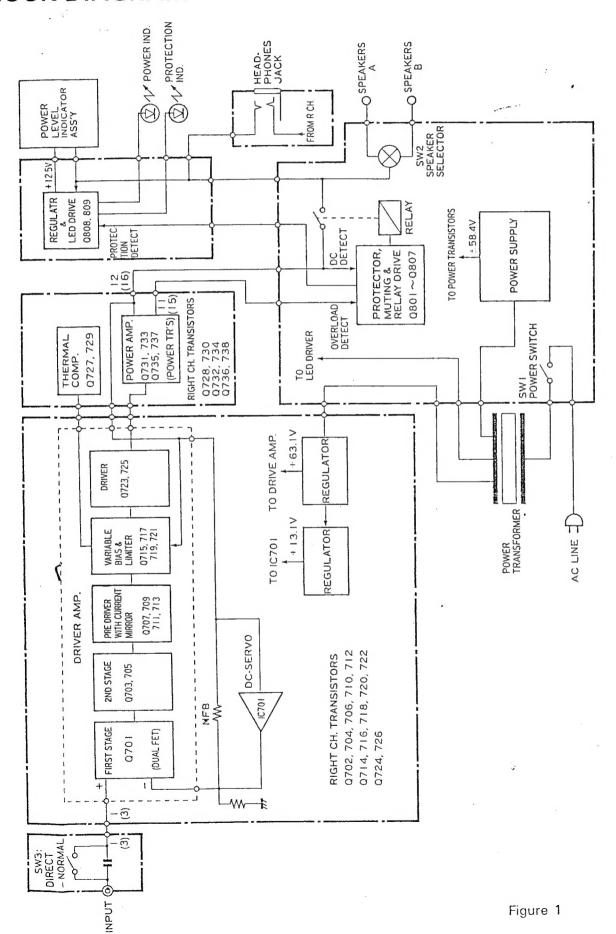
B-TYPE AC 240V, 50Hz

Power Consumption: 480 W (620 VA)

Ambient Temperature during Operation: ... $-10 \sim 30^{\circ}$ C

^{*}Specifications are subject to change without notice.

BLOCK DIAGRAM



DISASSEMBLY

CABINET COVER REMOVAL

- a. Remove four tapping screws from the top of the unit.
- b. Remove four screws from both sides of the unit.
- c. Lift the cabinet cover away from the unit.

BOTTOM PLATE REMOVAL

- a. Remove nine tapping screws from the bottom of the unit as shown in Photo 1. (#1 #9)
- b. Lift the bottom plate away from the unit.

FRONT PANEL REMOVAL

- a. Remove three tapping screws (#1 #3) from the left side of the unit as shown in Photo 2.
- b. Similarly remove three tapping screws from the right side of the unit.
- c. Remove the front panel away from the unit by pulling it forward.

POWER TRANSFORMER REMOVAL

- a. Remove the cabinet cover and the bottom plate.
- b. Disconnect all the cables from the power transformer.
- c. Remove four nuts (#1 #4) from the chassis as shown in Photo 3.
- d. Lift the power transformer away from the unit.

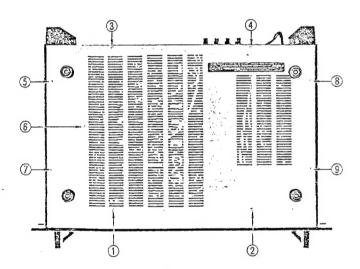


Photo 1

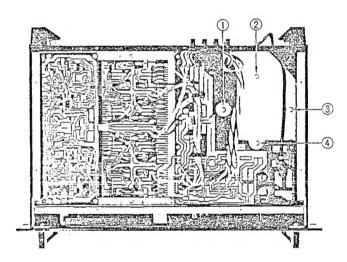


Photo 3

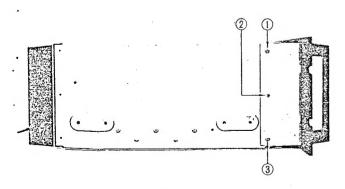


Photo 2

CIRCUIT DESCRIPTION

IIKKO's ALPHA 220, adopting latest devices such as li-fT power transistors, is of a design introducing a variable lias circuit (non-switching circuit), a DC servo circuit and other most advanced techniques.

For details, refer to page 2 "BLOCK DIAGRAM" nd page 8 "SCHEMATIC DIAGRAM".

The following are explanations of the main circuits nd devices.

VARIABLE BIAS CIRCUIT

Currently, in the output stage of power amplifiers are mostly used SEPP (Single Ended Push Pull) circuits. (Fig. 2).

It is generally known that the current (idle current) flowing through NPN and PNP transistors of this circuit can be classified into three large groups of operation form, class "A", class "AB" and class "B". (Fig. 3).

In class "A" operation, neither of collector currents, Q_1 and Q_2 , becomes zero nor cut off. Even when the current flowing to the load R_L is zero, a certain current is flowing through Q_1 and Q_2 , and so no crossover distortion exists theoretically.

To realize perfect class "A" operation, however, a current equal to or more than maximum output should continue to be let flow at the output stage as idle current, causing class "A" operation to prove to

be a poor efficiency system.

In class "AB" or "B" operation, the Ω_1 plays the role of amplification of the plus part of the signal and Ω_2 that of the minus part, no matter whether idle current is large or small.

In other words, there definitely exists a period in which, when one transistor is on, the other transistor keeps cutting off, in these operations.

Switching distortion or crossover distortion is caused at the moment of this active status turning into cut-off status or the cut-off status into the active status. Nevertheless, as these operation forms have high efficiency with small idle current, it is much easier to use class "AB" or "B" operation for high power amplification rather than class "A".

The idea of a variable bias circuit is that in no case the output stage is allowed to be cut-off by increasing and decreasing bias voltage in corresponding with the voltage of input signal.

Fig. 4 shows the variable vias circuit adopted in ALPHA 220.

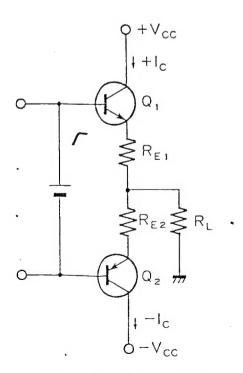


Figure 2 SEEP CIRCUIT

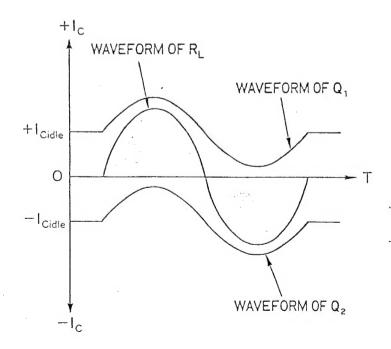


Figure 3-1 CLASS-A OPERATION

3. Hi-fT POWER TRANSISTORS

For detailes characteristics, refer to "SEMICONDUCTOR DATA" at the end of this manual.

The power transistors employed in ALPHA 220 realize an fT (Current Gain-bandwidth Product) of 80 MHz with NPN type and 60 MHz with PNP type (each being a typical value) in spite of its high Pc (Collector Power Dissipation) such as 150 W (The value when Tc = 25° C). Compared with conventional transistors with a Pc of 150 W where fT was around 10 MHz at maximum, the high speed attained by these Hi-fT power transistors is remarkable.

In this construction, the emitter inside the transistor is divided into many units and emitter resistors with small resistance are inserted to each unit, resulting in a parallel connection.

Figure 3-4 OPERATION OF BARIAVLE BIAS

This equivalently means that many small signal transistors with high fT and switching speed are parallelly connected, which has made it possible to realize such a high power characteristic while maintaining high switching speed.

Thanks to such construction as mentioned above, these power transistors are excellent in linearity of its hfe.

Furthermore, as dissipation is dispersed equally to each emitter due to the emitter-divided construction, they have another feature of being strong against breakdown as compared with conventional power transistors.

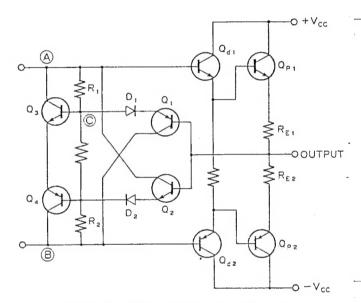


Figure 4 VARIABLE-BIAS CIRCUIT

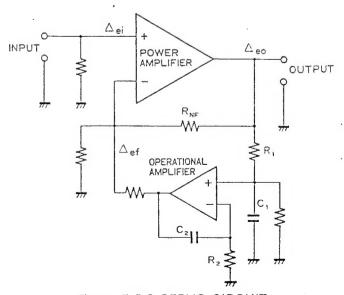
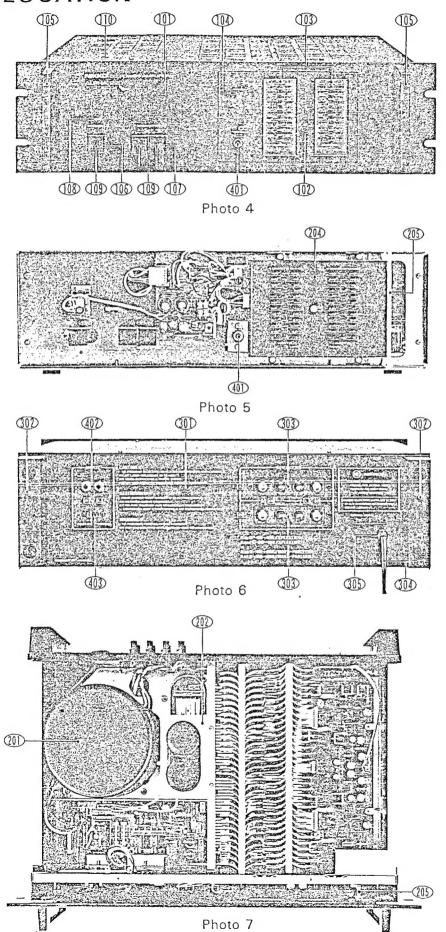


Figure 5 DC-SERVO CIRCUIT



PARTS LOCATION



ALIGNMENT

ALIGNMENT PRECAUTIONS

- 1. As the ALPHA 220 is a power amplifier with large output power, it consumes much electrical power and a great amount of current flows in the power source line of the primary side. Therefore, in the case when it is connected to the source by an extension cord, the size of the extension cord should be equal or larger than that of the power source cord of the ALPHA 220. Otherwise, the voltage might be reduced or the extension cord might generate excessive heat because of the resistance which the cord has, then not only can proper alignment be done, but also it is very dangerous.
- 2. If the power sources are supplied to the ALPHA 220 and the instruments by branching off from one cord, the voltage is sometimes dropped down and the stability of the instruments goes down.

 The ALPHA 220 and the instruments should be connected to the power sources by using independent cords. The ALPHA 220 must take the power source

from AC outlet of the wall side.

- 3. As there are many parts which hold high voltages in the circuit and the parts inside of the ALPHA 220, be careful not to receive an electric shock. In the case of connecting and taking off the instruments, you must turn off the power switch of the ALPHA 220 before getting on the work.
- 4. When the circuit happens to be shorted by the drivers or test probes used for alignment through mistake, the circuit and the parts will be damaged. As the damage is larger than that of ordinary amplifiers and receivers, close attention is needed. It is advised that the turning driver, excluding the top part, should be wrapped with insulation tape or a driver made of plastic or some kind of insulating material should be used.
- 5. As the dummy load resistor generates heat while alignment, it gets very hot and you may be burnt if you touch it with bare hands. It is better if you can put the dummy load resistor in a place away from being touched, but the wire between the dummy load resistor and the amplifier should not be long. Contrive some method, like putting the dummy load resistor in a well ventilated box. Further, as more than 5 A current might flow in the wire connecting the dummy load resistor and the amplifier, at least larger than AWG #18 thick wire should be used.
- 6. All the adjustments in the following should be done after the slide switch on the rear panel is set in the "NORMAL" position.

TEST EQUIPMENT

Allow a minimum of 10 minutes warm-up for test equipment.

Maintain rated line voltage.

Audio Frequency Generator
Distortion Meter
Oscilloscope
AC Voltmeter
DC Voltmeter
2-Dummy Load Resistors, 8 ohms, 250 W

All the semi fixed resistors of the MAIN AMP PCB are set around the center position temporarily. (HVR701 and HVR702.)

IDLING CURRENT ADJUSTMENT

- 1. Connect the 8 ohms dummy load resistors to the left and right channel speaker terminals.
- 2. Connect the DC voltmeter across the wireing terminal No. 12 and "TP-L" (left channel) or No. 16 and "TP-R" (right channel). (see Photo 8)
- 3. Turning on the power switch of the ALPHA 220. Adjust the semi fixed resistor HVR701 (left channel) or HVR702 (right channel) so that the DC voltmeter indicates $18 \text{ mV} \pm 1 \text{ mV}$.
- 4. Turn off the power switch of the ALPHA 220 and remove the DC voltmeter.

METER CIRCUIT ADJUSTMENT

NOTE: See illustration, Figure 8, for test equipment hook-up.

- 1. Connect 8 ohms dummy load resistors to the left and right channel speaker terminals.
- Connect the AC voltmeter, distortion meter and the oscilloscope to the left (right) channel speaker terminals. Connect the generator to left (right) channel input terminal.
- 3. Turning on the power switch of the ALPHA 220.
- 4. Set the frequency of the generator to 1 KHz. Adjust the output level of the generator so as to make the output power 98 W. (28 V AC voltmeter reading.)
- Adjust the semi-fixed resistors of the POWER LEVEL INDICATOR PCB, so that the LED of "120 W" dimly lights up.
- 6. Turning off the power switch of the ALPHA 220.
- 7. Remove all test equipment.

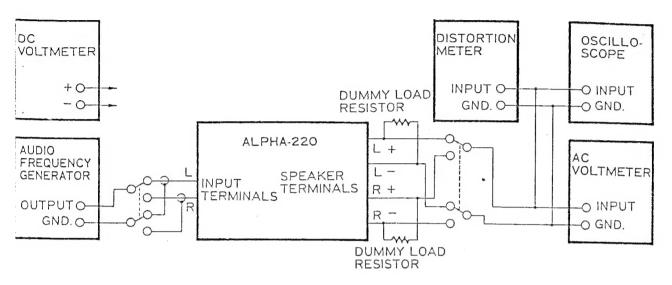


Figure 8 TEST EQUIPMENT HOOK-UP

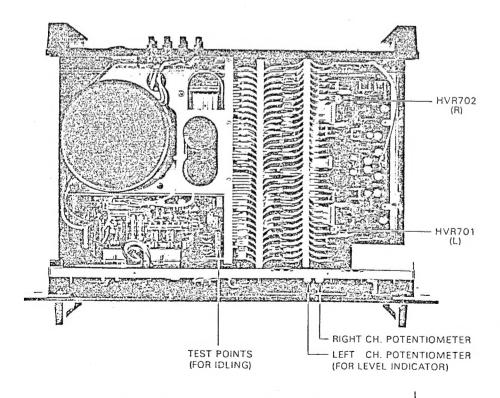


Photo 8 ADJUSTMENT POINTS

PARTS LIST

- 1. * The KEY NUMBER (#) marked with a (*) on parts list relate to number of three digits with a (). (Photo 4 ~ 7)
- 2. + Numberals in file indicate the quantity of parts used in one type.

3. ++ TR:

Transistor

FET: VR: Field effect transistor

Volume control (Variable resistor)

RES: MO-RES: Carbon film fixed resistor Metal oxide film fixed resistor

CEM-RES: FP: C-CAP: Cemented wirewound fixed resistor Flame proof Ceramic capacitor

E-CAP: M-CAP: S-CAP: T-CAP: Aluminum electrolytic capacitor Polyester film capacitor Polystyrene film capacitor Tantalum electrolytic capacitor Bipolar electrolytic capacitor

BP-CAP:

Low current leakage electrolytic capacitor.

- 4. Assemblies and parts are subject to change without notice.
- 5. Parts ordering procedure:
 - A. DO NOT USE THE "KEY" NUMBER AND "SYMBOL" NUMBER. (these are control # for the factory only)
 - B. Include in any order
 - a. Part number,
 - b. Part description
 - c. Model number.

(any of the above lacking from an order may delay shipment of that order.)

CAUTION:

The riangle mark, the KEY NO. and the SYMBOL NO. circled with rectangle in the schematic diagram and the shaded area in the parts list designate components which have special characteristics important for safety and should be replaced only with types identical to those in the original circuit or specified in the parts list.

KEY	SYMBOL	TYPE+		PART	1	KEY	SYMBOL	TYPE+		PART
			DESCRIPTION**						DESCRIPTION++	
NO.	NO.	WEB		NO.		NO.	NO.	WEB		NO.
	DAGKING	***	DIALS & ASSESSORIES		A	* 304a		1	Cord, AC line - SPT-1	606010A
į	PACKING	MAIL	RIALS & ACCESSORIES		A	± 304b ± 304c		-1 - 1	Cord, AC line — CEE-2T Cord, AC line — BS	600508A 600515A
001		111	Carton box	9825790	\triangle	* 305a		1	Bush, power card — SR-3P-4	7400620
002		222	Pad	9840970		★ 305b		-11	Bush, power cord — SR-4N-4	7400690
003		111	Sack, polyethylen cloth	9640740						
004 005a		111	Sack, polyethylen cloth — #13 Manual, instructions — English and French	9640320 960340E						
0056		-11	Manual, instructions — in five different	3003405						
			languages	960340K						
006		1	Manual, safety instructions	9670410						
007a		1	Card, warranty - U.S.A.	967043A						
0076	•	1	Card, warranty — Canada List, service stations	9670420 9690210						
009		111	Cord, RCA phono pin plug — 2T-1	962014A			MAIN AN	AP PC	BOARD ASSEMBLY	
		CABIN	NET ASSEMBLY					(POWE	R OUTPUT SECTION)	
							Q727,728	222	TR 2SD682 (P or Q)	5 131195
* 101a		111	Panel, front - SILVER	7885060			0729,730	222	TR 2S8772 (P or Q)	5 11120S
*1016 *102a		111	Panel, front – BLACK	7885050 7870540			Q731,732, Q735,736		70.0007535 (0 - 0)	5 401070
*102b		111	Panel, power level indicator - SILVER Panel, power level indicator - BLACK	7870540			Q733,734,	444	TR 2SC2565 (O or R)	5 121275
*103		111	Window, power level indicator	7802650			Q737,738	444	TR 2SA1095 (O or R)	5 101238
±104		111	Globe, LED - protection indicator	7402540			,			
*105a		222	Handle - 100G - SILVER	7490180			C741,742	222	M-CAP 0.047uf 10% 400V	2 73473K
* 1055		222	Handle - 1003 - BLACK	7490190			C743			
*106 *107		111	Guide, button – 1918 – power switch	7402550			~ C746	444	E-CAP 1uf 100V	2 118100
*108		111	Guide, button – 2918 – speakers selector Globe, LED – input power indicator	7402560 7402120			R781			
			order, EED Superporter mercarer	, 102120			~ R728	888	CEM-RES 0.1ohm 2Wx2	3.82109P
*109a		3 3 3	Button, push - M18GL - power/speakers,				R789,790	222	FP-MO-RES 10ohm 2W	362100L
*109b	1	333	SILVER Button, push - M188K - power/speakers,	7852290				IDRIV	ER PCB SECTION)	
ŀ			BLACK	7852300			10301		10.4110550	- 400000
*110		111	Cover, top	7821110			IC701	111	IC AN6552	5 18096\$
	.*						Q701,702	222	FET 2SK 150A (GR)	5 16038\$
111		111	Plate, bottom	7326430	}		Q703			
112		4 4 4	Foot, polysthylen – 22¢x10	7401350			~ Q706 Q707	444	TR 2SC1845 (E or F)	5 121155
							~ 0710	444	TR 2SA1144 (O or Y)	5 10120S
		CHAS	SIS ASSEMBLY				0711,712	222	TR 2SC1941 (L or K)	5 12112S
							Q713,714	222	TR 2SC2704 (O or Y)	5 121225
*201a		1	Transformer, power - T-1-397 - AC 120V	1103970			Q715,716	222	TR 2SA992 (E or F)	5 101108
± 2016)	-11	Transformer, power - T-1-413 - AC220 or	1104130			0717,718	222	TR 2SC1845 (E or F)	5 121158
*202		111	240V Supporter, filter capacitors	7002510			Q719,720 Q721,722	222	TR 2SC1815 (Y or GR) TR 2SA1015 (Y or GR)	5 12107S 5 10102S
	,						Q723,724	222	TR 2SC2275 (P or Q)	5 121205
203		111	Power level indicator assembly	4582770			Q725,726	222	TR 2SA985 (P or Q)	5 101185
*204		1 1 1	Inside panel, power level indicator	7802660						
* 205		111	Light guide, level indicator	7401580			D701		E:	
206		1 1 1	Lamp — 8V 0.3A	5808210			~ D704 D705	4 4 4	Diode 2-0A90	5 © 00013G
							~ D708	444	Diode 1S2076	5 010198
		BACK	PLATE ASSEMBLY				D709,710	222	Diode GP10-4002	5 £30066S
							D802	111	Diode W02	5 \$ 0061S
*301a		1	Plate, back — (\V)	7326390			ZD701		_	
★301 8	5	-11	Plate, back — (E)	7326400			~ ZD704		Zener diode RD22EB4	5 402059\$
1 3016					1	I	ZD705,706	222	Zener diode RD13EB3	5 4 02063S
*302		222	Block, terminal guard	7401860						3
		222	Block, terminal guard Terminal, speakers — screw type 4P	7401860 4450480			TH701 ~ TH704		Thermistor D2FHL-103S	5 400180

PART ORDERING PROCEDURE DO NOT USE THE "KEY" NUMBER AND "SYMBOL" NUMBER. (these are control # for the factory only.) Include in any order: a. Part number, b. Part description, c. Model number. (any of the above lacking from an order may delay shipment of the order.)

Description														
NO. NO. W. E.B.	KEY	SYMBOL	TYPE+	1			PART	KEY	SYMBOL	TYPE	0.500.010.714	++		PART
Change Company Compa		NO	W C D	DESCRIP	TIONTT		NO	NO	NO.	WEB	DESCRIPTION	JIN		NO.
COURT 24 CAP Light 100 200	NO.	NO.	WEB											
COURT 144 6 ECAP 1004 259 22 22 CAP 5006 10% 5007 22101KL CRIT1.712 222 MCAP 0.047 10 100 2007 2747KK CRIT1.712 222 MCAP 0.047 10 100 2007 2340KK CRIT1.712 222 CAP 60 10% 5007 2340KK CRIT.713 234 24 6 FES 27.05mm 5% 5W 208692 CRIT.713 222 RES 27.05mm 5% 5W 20869			222	C-CAP 100pf 10%	50V		232101K	1						512108S 510110S
C109,719 2.22 CAP MIGGS 10% SOV 22151K C111,714 22.20 CAP MIGGS 10% SOV 22450K C113,714 27.2 CAPS 6pt 10% 500V 22450K C113,714 27.2 CAPS 6pt 10% 500V 22450K C115,715 27.2 CAPS 6pt 10% 500V 22450K C115,715 27.2 CAPS 6pt 10% 500V 22450K C115,717 27.2 CAP		C705												5121075
C711,712 222 ACAP Dishel 1st 200V 2749786 C113,716 222 CAP 3et 1 5t 500V 245096 C113,716 222 CAP 3et 1 10% 500V 2745096 C117,719 222 CAP 3et 1 10% 500V 2745096 C117,719 222 CAP 3et 1 10% 500V 2745096 C117,719 222 CAP 3et 1 10% 500V 2745096 C127,717 222 CAP 3et 1 10% 100V 2745096 C127,717 222 CAP 3et 1 100M 80V 2745096 C127,7		~ C708	444	E-CAP 100uf 25V				1						5101025
C113,714 222 CCAP fair 10% 500V 234509K C117,718 222 CCAP 247 10% 500V 234509K C117,718 222 CCAP 247 10% 500V 234509K C117,718 222 CCAP 247 10% 500V 234509K C127,718 222 CCAP 247 10% 500V 234509K C127,718 222 CCAP 247 10% 500V 234509K C123,734 227 8F-CAPROUL 18V 215230N C123,734 227 8F-CAPROUL 18V 215230N C212,737 222 ECAP 1004 80V 2102303 C003,848 222 ECAP 1004 80V 2102303 C003,849 222 ECAP 1004 8		C709,710	222	·]						5121095
C119,718 222 C-CAP 3rd 10% 500V 234409K C119,710 222 C-CAP 100pd 10% 500V 234407K C119,710 222 C-CAP 100pd 10% 500V 234407K C127,772 222 BC-CAP 100pd 10V 21522W C227,773 222 BC-CAP 100pd 10V 21522W C203,564 222 E-CAP 100pd 10V 21522W C203,564 222 E-CAP 100pd 10V 21522W C203,564 222 E-CAP 100pd 10V 21522W C203,574 222 BC-CAP 100pd 10V 21522W C	1	C711,712	222	M-CAP 0.047uf 10%				1						
C117,113 212 CAP 47st 10% 500V 234470K C191,70 212 CAP 505 C191,70 212 CAP 505 C191,70 212 CAP 505 C191,70 212 CAP 505 C191,70 212 C	-	C713,714	222	C-CAP 6pf 10%	500\	/	Į.		Q807	111	TR 2SC2240 (Y or GR)			5121028
C19-770 222 C CAP 100pt 100k 5000 234101K	1	C715,716	222	C-CAP 3pf 10%	500\	/								- 1
C131.79	1	C717,718	222	C-CAP 47pf 10%	500\	/	234470K							5010000
C175.176 222 BFCARROW 16V 2152004 C175.778 222 ECAP 1004 16V 215204 C175.778 222 ECAP 1004 16V 215204 C275.778 222 R55 2.766 5% WW 328721 C275.778 222 F66.776 5% WW 328721 C275.778 222 F676.776 5% WW	1	C719,720	222	C-CAP 100pf 10%	500\	/	234101K	1						501020S
C723,78 222 BFCAPOOUT 16V 21520M C725,78 222 BFCAPOOUT 16V 21520M C727,78 222 ECAP 100Ur 16V 21520M HVR701 HVR701 F702 222 R5 2.7 bohm 5% 5% 5% 3382431 R701,720 222 R5 2.7 bohm 5% 5% 5% 3382431 R701,720 222 R5 2.7 bohm 5% 5% 5% 3382431 R701,720 222 R5 2.7 bohm 5% 5% 5% 3382431 R701,720 222 R5 2.8 bohm 5% 5% 5% 3382431 R701,720 222 R5 5.8 bohm 5% 5% 5% 3382431 R701,720 222 R5 5.8 bohm 5% 5% 5% 3382431 R701,720 222 R5 5.8 bohm 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 5% 3385431 R701,720 222 R5 5.8 bohm 5% 5% 5% 5% 58 58 58 58 58 58 58 58 58 58 58 58 58		C721,722	222	BP-CAP 22uf 16V			215222N	1	D808	111	Diode GP10-4002			5600668
C225,782 222 EPCAP 2791 180V 2192200 C227,782 222 ECAP 1000x1 80V 219200 C203,884 222 ECAP 1000x1 80V 219200 C203,884 222 ECAP 1000x1 80V 219200 R701,702 222 Potentiometer Shohm 4301410 R701,702 222 Potentiometer Shohm 5% WW 3380721 R701,703 222 RES 127.00hm 5% WW 3380721 R701,704 222 RES 127.00hm 5% WW 3380721 R701,705 222 RES 127.00hm 5% WW 3380721 R701,707 444 RES 127.00hm 5% WW 3380721 R701,707 222 RES 100.00hm 5% WW 3281011 R701,702 222 RES 100.00hm 5% WW 3281011 R701,703 222 RES 100.00hm 5% WW 3282011 R701,703 222	-	C723,724	222	BP-CAP100uf 16V			215230N	1						
CR03 SM 222 ECAP 1000uf 80V 2100130 LT07.702 222 Call. choice - Livif LT07.702 Call LT07		C725,726	222	BP-CAP 22uf 16V			215222N		ZD801	111	Zener diode RD22EB4			5020595
C803,852 22.2 ECAP 1000uf BOV 2100130 C807.80 22.2 C81.00toke - INF C807.80 C807		C727,728	222	E-CAP 100uf 16V			211230Q	1						
## ## ## ## ## ## ## ## ## ## ## ## ##				E-CAP 1000uf 80V			2100130		L701,702	222	Coil, choke - 1uH			1210960
## ## ## ## ## ## ## ## ## ## ## ## ##		UV 8 701							C807,808	222	BP-CAP 1uf 50V			215510N
R701,722 22 R5S 2,7k-bm 5% XW 328272, R703,754 222 R5S 6,8k-bm 5% XW 328473, R705,756 222 R5S 100blm 5% XW 328101, R711,712 222 R5S 100blm 5% XW 328101, R711,712 222 R5S 100blm 5% XW 328510, R711,718 222 R5S 560blm 5% XW 328511, R711,718 222 R5S 500blm 5% XW 328511, R711,718 222 R5S 100blm 5% XW 328511, R711,718 222 R5S 80blm 5% XW 328511, R711,712 R5 222 R5S 100blm 5% XW 328511, R711,712 R5 222 R5S 100blm 5% XW 328511, R711,712 R5 222 R5S 100blm 5% XW 328511, R711,712 R5 222 R5 10blm 5% XW 328511,]		222	Porentinmeter Skohm			4301410				E-CAP 1uf 50V			2115100
R201/20 222 R5 47xbm 5% XW 338473/ R703,769 222 R5 6,Bk0hm 5% XW 338473/ R705,769 222 R5 1,Bk0hm 5% XW 338473/ R705,769 222 R5 1,Bk0hm 5% XW 338473/ R711,712 222 R5 1,Bk0hm 5% XW 338473/ R711,712 222 R5 1,Bk0hm 5% XW 338513/ R711,713 222 R5 1,Bk0hm 5% XW 338513/ R712,714 212 R5 1,Bk0hm 5% XW 338513/ R712,716 444 FARG 8,Bk0hm 5% XW 328173/ R713,716 227 R5 1,Bk0hm 5% XW 338513/ R713,716 444 R5 8,7xchlm 5% XW 338513/ R713,716 444 R5 1,80chlm 5% XW 328513/ R713,717 4 222 R5 1,80chlm 5% XW 328513/ R713,718 4 222 R5 1,80chlm 5% XW 328513/ R713,718 4 4 4 8 8 8 1,80chlm 5% XW 328513/ R713,718 4 4 8 8 8 1,80chlm 5% XW 328513/ R713,718 4 4 8 8 8 1,80chlm 5% XW 328513/ R713,718 4 4 8 8 8 1,80chlm 5% XW 328513/ R713,718 4 4 8 8 1,80chlm 5% XW 328513/ R713,718 4 4 8 8 1,80chlm 5% XW 328513/ R713,718 4 4 8 8 1,80chlm 5% XW 328513/ R713,718 4	1	702	222	rotetttometer skonti				i			8P-CAP 100uf 10V			215130N
## ## ## ## ## ## ## ## ## ## ## ## ##	1	D701 702	222	DES 27kohm	E04	'ZW	328272.1	1		111	E-CAP 47uf 25V			2113250
### ### ### ### ### ### ### ### ### ##	1									111	E-CAP 10uf 16V			2112200
### RESULT								1			E-CAP 1uf 50V			2115100
### R710	1		2 2 2	nes blokomm	3.6	7244	0200023		55.5					
R311,172	1		444	DCC 274-b-	5%	1/.W	3282721	1	B791 792	722	FP-MO-RES 10ohm	5%	2W	362100L
R313 R315 R316 R317 R317 R318 R317 R317 R318 R317 R317 R318 R318 R317 R318 R311 R318	ł						- 1	1						328222J
No.	ļ		222	HES TOUGHM	J.0	-417	020.013							328223J
R117,718 22 RES 5600hm 5% XW 328153J R809 111 RES 580chm 5% XW XW XW XW R119,70 22 RES 150chm 5% XW 328153J R809 111 RES 100cchm 5% XW XW XW XW R125,708 22 RES 4,7bchm 5% XW 328272J R127 R1	ŀ			ED MO DEC E COL	E 6/	114/	3615631	1						328823J
R117,172 22	ı						1							328563J
### R25 R2	1													328183J
### A 44 # RES 47kohm 5% XW 328472J R910,211 22 RES 88kohm 5% XW 328472J R9172728 22 RES 820kohm 5% XW 328272J R9172729 RES 27kohm 5% XW 328101J R918 11 RES 47kohm 5% XW 328101J		R719,720	222	RES 15kohm	5%	%W	3281533							328104J
## R12	1	R721						1						328683J
R725, //6 22 2 RES 820hm 5%	-	~ R724	444	RES 4,7kohm	5%		1							328472J
R730 4 44 RSS 820ohm 5% XW 328821J R814 11.1 RSS 470ohm 5% XW 328910J R731,732 2.2 RSS 820ohm 5% XW 328910J R815 11.1 RSS 270ohohm 5% XW 32810J R815,735 2.2 RSS 820ohm 5% XW 32810J R815 11.1 RSS 470ohohm 5% XW 32810J R815,735 2.2 RSS 820ohm 5% XW 32810J R816 11.1 RSS 470ohohm 5% XW 32810J R745,745 2.2 RSS 180ohm 5% XW 32810J R755 R756 4.44 FP.RSS 820ohm 5% XW 32810J R759,755 R758 4.44 FP.RSS 820ohm 5% XW 32810J R759,755 2.2 RSS 180ohm 5% XW 32810J R759,756 2.2 RSS 180ohm 5% XW 3	1	R725,726	222	RES 2.7kohm	5%	%W	328272J							
R731732 22 RES 820mm 5% XW 328301 R815 111 RES 270chm 5% XW 328101 R733,734 22 RES 180chm 5% XW 328101 R815 111 RES 270chm 5% XW 328101 R815 111 RES 270chm 5% XW XW XW XW XW XW XW X	i	R727					1							328154J
R731/34 22	1	~ R730	444	RES 820ohm	5%	%W	328821J	1	R814					328470
### R733,736 222 FPM.ORES 3.9kohm 5% XW 328101J R816 111 RES 4.7kohm 5% XW 328101J R747,737 ### R740 444 RES 180ohm 5% XW 328101J R741,742 222 RES 1kohm 5% XW 328101J R745,745 222 RES 1kohm 5% XW 328102J R747 ### R750 444 FP.RES 200hm 5% XW 32821L R755 ### R751 ### R755 ### R759,750 22 2 FPM.ORES 270ohm 5% XW 328301L R759,750 22 2 FPM.ORES 300hm 5% XW 328301L R761,752 222 FPM.ORES 270ohm 5% XW 328101J R761,752 222 FPM.ORES 270ohm 5% XW 328101J R767,768 222 FPM.ORES 25.6kohm 5% XW 328101J R767,768 222 FPM.ORES 25.6kohm 5% XW 328103J R767,768 222 FPM.ORES 25.6kohm 5% XW R819 111 FP.RES 270ohm 5% XW R819 111 FP		R731,732	222	RES 82ohm	5%	%W	328820J		R815	111				328224J
R735,736 22 FP.M.O.RES 3.9kohm 5%				RES 100ohm	5%	WW.	328101J	1	R816	1.1.1	RES 4.7kohm			328472J
~ R740 4.4 4 RES 1800hm 5% XW 328181J R741,712 2.2 RES 1800hm 5% XW 328182J R743,714 2.2 RES 1800hm 5% XW 328182J R747 R747 R750 4.4 4 FP-RES 2200hm 5% XW 328221L Q809 111 TR 25C2275 (P or QI)		R735,736		FP-MO-RES 3.9kohr	n 5%	1W	361392L		R817	111	FP-MO-RES 1kohm	5%	11/4	361 (02L)
R741,712 222 RES 1kehm				DCC 180-b-	52/	1/14/	3281811							- 1
R743,144 2 2 2 RES 1.8kshm 5% MW 3281821 R745,146 2 2 2 RES 1.8kshm 5% MW 3281821 R747										DHEAD	PHONES PCR SECTION	1)		1
### R745 / R8										11.27	311101120 1 00 0001111	•		
R747								+401		1 1 1	lack headphones			4550260
R751 R751 - R754 R755 - R754 R755 - R758 - R758 - R758 - R759,750 - 22 2 FP-MO-RES 2700hm 5%			222	RES Ikohm	5%	74 VV	3281023	1-401			Jean, Hecepitalies			
R751	- }					20141	2202211		0000	1 1 1	TR 2502275 IP or 01			51212CS
			4 4 4	FP-RES 2200nm	5%	74 VV	3202216					11		5121075
R755	}					*****	220224		0009	111	11 230 1013 (1 01 01			
A7.93 4.44 FP.RES 390ohm 5% WW 328391L R759,750 22.2 FP.MO.RES 270ohm 5% WW 328104J R761,792 22.2 RES 100kohm 5% WW 328103J R763 R766 4.44 RES 10kohm 5% WW 328103J R767,768 2.2.2 FP.MO.RES 5.6kohm 5% WW 328103J REGULATOR PC BOARD ASSEMSLY C816 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C818 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C818 1.11 E-CAP 330Jr 25V C817 1.11 E-CAP 330Jr 25V C818 1.11 E-CAP 330Jr 25V R818 1.11 FERS 270chm 5% WW R819 1.11 <			4 4 4	FP-RES 820ohm	5%	% VV	325821L		0000 910	222	Diode GP10-4002			560066S
R759,760 2 2 2 FP-MO-RES 270ohm 5% 1W 361271L 328104J R761,782 2 2 2 RES 100kohm 5% 1W 328104J R763 R763 R763 R763 R765 R766					F 64	herae	2222011		0005,010	222	D1006 01 10-4002			
R761,762 22 2 RES 100kohm 5%	j						1		30903	111	Zanar diada BO13E83			5020638
R763							1		20002	117	Zener diode RD15055			
~ R755		R761,762	222	RES 100kohm	5%	%W	328104J	1			5010171101			2112250
R767,768 2 2 2 FP-MO-RES 5.6kohm 5% 1W 361562L REGULATOR PC BOARD ASSEMSLY (REGULATOR SECTION) R801 1 Fuse - 8A 250V MGC 4700760 R802,803 2 Fuse - 0.8A 250V MGC 4700580 R819 111 RES 1.5kohm 5%	ł	R763												2113330
REGULATOR PC BOARD ASSEMBLY (REGULATOR SECTION) A F801 1 Fuse - 8A 250V MGC 4700760 F802,803 2 Fuse - 0.8A 250V MGC 4700580 A F802,803 2 Fuse - 0.8A 250V MGC 4700580 A F801 -11 Midget fuse - T4.0A 250V 4720400 F802,803 -11 Midget fuse - T0.8A 250V 4720320 A SW1 1 Switch, push - SDZ-1P TV-8 - power 5W1 -11 Switch, push - ESB-90179S - power 4041500 SW1 -11 Switch, push - ESB-90179S - power 4041600 C C C C C C C C C C C C C C C C C C	1	~ 8766	444	RES 10kohm	5%			1						
REGULATOR PC BOARD ASSEMBLY (REGULATOR SECTION) A F801 1 Fuse - 8A 250V MGC 4700760 A F802,803 2 Fuse - 0.8A 250V MGC 4700580 A F802 Fuse - 0.8A 250V MGC 4700580 A F802,803 1 Midget fuse - T4.0A 250V 4720320 A SW1 1 Switch, push - SDZ-1P TV-8 - power 5W1 - 11 Switch, slide - SS8-022 - normal-direct selector SW1 1 -1 Switch, push - ESB-90179S - power 4041500 D801 111 Diode S10V820 5600585 C C C C C C C C C C C C C C C C C C C		R767,768	222	FP-MO-RES 5.6koh	m 5%	1W	361562L	1						2113300
REGULATOR SECTION Regulat								1	C817	111	E-CAP 33uf 25V			2113230
REGULATOR SECTION Regulat	{		, , , ,	D DO DOADD 20	CENADA '	v			0702704	, ,,,	ED-WO-BES 3300pm	5%	2W	362331L
(REGULATOR SECTION) A F801 1 Fuse - 8A 250V MGC 4700580 A F802,803 2 Fuse - 0.8A 250V MGC 4700580 A F802,803 2 Fuse - 0.8A 250V MGC 4700580 A F802,803 -11 Midget fuse - T4.0A 250V 4720400 A F802,803 -11 Midget fuse - T0.8A 250V 4720320 A SW1 1 Switch, push - SDZ-IPTV-8 - power 4041500 SW1 -11 Switch, push - ESB-90179S - power 4041600 D801 111 Diode S10VB20 560058S C801,802 2 2 2 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -11 M-CAP 0.01uf 250V 283103M (PROTECTOR SECTION) R819 111 RES 1.5kohm 5% ¼W R821 111 RES 220kohm 5% ¼W R822 111 FP-RES 270ohm 5% ¼W R822 111 E-PRES 270ohm 5% ¼W R822 111 FP-RES 270ohm 5% ¼W R822 111 FP-RES 270ohm 5% ¼W R822 111 FP-RES 270ohm 5% ¼W R821 111 RES 1.5kohm 5% ¼W R822 111 RES 1.5kohm 5% ¼W R822 111 RES 1.5kohm 5% ¼W R822 111 FP-RES 270ohm 5% ¼W R821 FI SP-RES 270ohm 5% ¼W R822 111 FP-RES 270ohm 5% ¼W R821 FI SP-RES 270ohm 5% ¼W R822 111 FP-RES 270ohm 5% ¼W R822	1	REG	ULAIO	IN PU BUAND AS	PEINIT	1			•					329271L
R821 111 RES 220kohm 5% WW							- 1							328152J
A F801 1 − − Fuse − 8A 250V MGC 4700760 A F802,803 2 − − Fuse − 0.8A 250V MGC 4700580 B 1 − 1 1 Midget fuse − T4.0A 250V 4720400 B 1 − 1 1 Midget fuse − T0.8A 250V 4720320 B 1 − − 2 Switch, push − SDZ-1P TV-8 − power 4041500 B 1 1 1 Switch, push − SDZ-1P TV-8 − power 4041500 B 1 1 1 Diode S10V820 560058S C C801,802 2 2 2 E-CAP 15000uf 71V 2100120 C C806 1 − − M-CAP 0.01uf 125V 284103M C C806 − 1 1 M-CAP 0.01uf 250V 283103M C PROTECTION SECTION)	1		(REG	ULATOR SECTION)			1							328224J
F802,803 2 Fuse - 0.8A 250V MGC 4700580 F801 -11 Midget fuse - T4.0A 250V 4720400 F802,803 -11 Midget fuse - T0.8A 250V 4720320 SW1 1 Switch, push - SDZ-1P TV-8 - power 5W1 -11 Switch, push - ESB-90179S - power 4041500 D801 111 Diode S10V820 560058S C801,802 222 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -11 M-CAP 0.01uf 250V 283103M (PROTECTOR SECTION) (PROTECTOR SECTION) (PROTECTOR SECTION) (INPUT PCB SECTION)														329271L
F801	4						1		R822	111	Fr-RES 2700hm	276	73.44	0202716
A F801 −11 Midget fuse − T4.0A 250V 4720400 A F802,803 −11 Midget fuse − T0.8A 250V 4720320 ★ SW1 1 − - Switch, push − SDZ-IP TV-8 − power 4041500 ★ SW1 −11 Switch, push − ESB-90179S − power 4041600 D801 111 Diode S10V820 560058S C801,802 2 2 2 E-CAP 15000uf 71V 2100120 C806 1 − - M-CAP 0.01uf 125V 284103M C806 −11 M-CAP 0.01uf 250V 283103M LED801 111 LED R55527S 111 Spacer, LED (PROTECTION INDICATOR SECTION) LED802 111 Spacer, LED	\triangle	F802,803	2	Fuse - 0.8A 250V I	MGC		4700580							
#402 #403 #402 #403 #402 #403 #403 #403 #403 #403 #403 #403 #403	1						1			(INPI	JT PCB SECTION)			
#402	\triangle	F801	-11	Midget fuse - T4.0A	4 250V									4440070
SW1 1 Switch, push - SDZ-IP TV-8 - power 4041500 SW1 -1 Switch, push - ESB-90179S - power 4041600 D801 11 Diode S10V820 560058S C801,802 2 2 2 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -1 1 M-CAP 0.01uf 250V 283103M (PROTECTION INDICATOR SECTION) LED802 11 LED PR5527S 11 LED PR5527S 11 Spacer, LED	<u>A</u>		-11	Midget fuse - T0.84	4 250V		4720320	*402	?		Terminal, RCA phono	pin jack	k – 2P	4442070
SW1 -11 Switch, push - ESB-90179S - power 4041600 D801 111 Diode S10VB20 560058S C801,802 222 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -11 M-CAP 0.01uf 250V 283103M (PROTECTOR SECTION) LED801 111 LED BR5504S 111 Spacer, LED (PROTECTION INDICATOR SECTION) LED802 111 LED PR5527S 111 Spacer, LED	ļ	-,						*403	1	111		2 - no	rmal-direct	
△ SW1 -11 Switch, push - ESB-90179S - power 4041600 ○ D801 111 Diode S10V820 560058S ○ C801,802 2 2 2 E-CAP 15000uf 71V 2100120 ○ C806 1 M-CAP 0.01uf 125V 284103M ○ C806 -1 1 M-CAP 0.01uf 250V ○ C806 -1 1 M-CAP 0.01uf 250V ○ C806 -1 1 LED801 ○ C806 -1 1 LED802 ○ C806 -1 1 LED PR5527S ○ C806 -1 1 LED802 ○ C806 -1 1 LED PR5527S ○ C806 -1 1 LED802 ○ C807 -1 1 LED802 ○ C808 -1 1 LED802 ○ C809 -1 1 LED802 ○ C809 <t< td=""><td>Δ</td><td>SW1</td><td>1</td><td>Switch, push - SDZ</td><td>-1P TV-8</td><td>- power</td><td>4041500</td><td>-1</td><td></td><td></td><td>selector</td><td></td><td></td><td>4020710</td></t<>	Δ	SW1	1	Switch, push - SDZ	-1P TV-8	- power	4041500	-1			selector			4020710
D801 111 Diode S10V820 560058S C801,802 2 2 2 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -1 1 M-CAP 0.01uf 250V 283103M (PROTECTOR SECTION) C701,702 2 2 2 8P-CAP 2.2uf 50V (POWER INDICATOR SECTION) LED801 111 LED BR5504S 111 Spacer, LED (PROTECTION INDICATOR SECTION) LED802 111 LED PR5527S 111 Spacer, LED							4041600							ا
D801 111 Diode \$10V820 560058\$ C801,802 2 2 2 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -1 1 M-CAP 0.01uf 250V 283103M LED801 111 LED BR5504S (PROTECTOR SECTION) LED802 111 LED PR5527S 111 Spacer, LED				2		•			C701,703	2 2 2 2	BP-CAP 2.2uf 50V			215512N
(POWER INDICATOR SECTION) C801,802 222 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -1 1 M-CAP 0.01uf 250V 283103M (PROTECTOR SECTION) (PROTECTOR SECTION) (PROTECTOR SECTION) (PROTECTOR SECTION)	1	0801	111	Diode S10V820			5600585		•					
C801,802 2 2 2 E-CAP 15000uf 71V 2100120 C806 1 M-CAP 0.01uf 125V 284103M C806 -1 1 M-CAP 0.01uf 250V 283103M 111 LED 8R5504S (PROTECTOR SECTION) LED802 111 LED PR5527S 111 Spacer, LED (PROTECTOR SECTION)		2001		5.000 5.0.020						(POV	ER INDICATOR SECTION	ON)		
C806 1 M-CAP 0.01 uf 125V C806 -1 1 M-CAP 0.01 uf 250V 284103M C806 -1 1 M-CAP 0.01 uf 250V 283103M LED801 111 LED BR5504S 111 Spacer, LED (PROTECTION INDICATOR SECTION) LED802 111 LED PR5527S 111 Spacer, LED	1	CB01 802	222	E-CAP 15000uf 7	1 V		2100120	1		-				
C806 -11 M-CAP 0.01uf 250V 283103M 111 Spacer, LED (PROTECTION INDICATOR SECTION) LED802 111 LED PR5527S 111 Spacer, LED	Δ								LED801	111	LED BR5504S			5060300
(PROTECTION INDICATOR SECTION) LED802 111 LED PR5527S (PROTECTOR SECTION) 111 Spacer, LED														7903140
(PROTECTOR SECTION) LED802 111 LED PR5527S 111 Spacer, LED		COUB	-11	11-0/A 0.0101 2301										
(PROTECTOR SECTION) 111 Spacer, LED										(PRC	TECTION INDICATOR	SECTI	ON)	
(PROTECTOR SECTION) 111 Spacer, LED	1								I Enona	111	1 ED PR55779			5060270
404700			(PRC	TECTOR SECTION)					LED802					7903110
Sw2 3			,											
		SW2,3	111	Switch, twin push -	- SUF-24	- speakers	4041590							
RELAY1 111 Relay - G2Z-222P - DC24V 1700300		REL AY1	111	Relay - G2Z-222P	- DC241	/	1700300							

SEMICONDUCTOR DATA

TRANSISTORS

† NOTE

Se: Germanium

A : Alloy

Df: Drift-field E: Enitaxial M : Mesa

: Planer : Point-cont

	Si:	Sillicon	

A	1	CHARACTERISTICS	Typical	Values:
d	:	Double-diffused	J	Junct
	:	Diffused	G	
		Case	_	. cp.ce

						re-Maximum rise specified			- 1	LECTRIC	AL CH	ARACTE	RISTICS	Typical	Value	s: (T _A = 2	5°C u	nless oth	erwise spe	cified)	
DEVICE	APPLICATIONS	STRUC- TURET	Collector- to-Base Voltage VCBO (V)	Emitter- to-Base Voltage VESO (V)	Callector Current Ic (mA)	Collector Dissipa- tion PC (mW)	Junction Tempera- ture TJ (^a C)	Collector C Curren ICBO (uA)		Static Franchise Train	VCE		Collecto Saturatio VCE(sat) (V)	lc		Gain-Band f _T fob* (MHz)	VCE VCB*	IC.	Output Capaci- tance Cob (pF)	Others	MANU. FACTURES
25A985 (P. Q)	AF, Power amp.	PNP Si-E	- 120	-5	~ 1.5A	25W (Tc=25°C)	150	~† max.	120	100 ~ 320	-5	_ 300	-2 max.	1 A	- 100	180	5	- 200 °	29	Complementary to 25C2275	NEC
25A992 (E, F)	AF, Low noise	PNP Si-E	-120	-5	- 50	500	125	-0.05 max.	- 120	300 ~ 800	~6	0.1	-0.3 max.	10	-1	100	-6	1	3 max.	Complementary to 25C1845	NEC
25A1015 (Y, GR)	AF. General	PNP Si-E	-50	-5	-150	400	125	-0.1 max.	-50	120 ~ 400	6	-2	-0.3 max.	- 100	- 10	80 min.	- 10	-1*	7 max.	Complementary to 25C1815	TOSHIBA
2SA1095 (O. R)	AF, Power amp.	PNP Si-E	-160	-5	-15A	150W (Tc=25°C)	150	~ 50 max.	- 160	55 ~ 160	-5	-1A	-2 max.	-5A	- 500	60	- 10	- IA*	350	Complementary to 25C2565	TOSHIBA
2SA1144 IO, YI	AF, Driver	PNP Si-E	-150	-5	50	10W (Te=25°C)	150	-0.1 max.	- 150	80 ~ 740	- 5	10	1 max.	-10	-1	120	- 5	-10'	2.5	Complementary to 25C2704	TOSHIBA
258772 (P, Q)	AF, Power amp,	PNP Si-E	-40	~5	-3A	1W	150	-1 max.	-30	100 ~ 320	-2	-20	-0.5 max.	-2A	-200	80	- 5	100	55	Complementary to 25D88Z	NEC
25C1815 (Y, GR)	AF, General	NPN Si-E	60	5	150	400	125	0.1 max.	60	120 ~ 400	6	2	0.25 max.	100	10	80 min.	10	1.	a max.	Complementary to 2SA1015	TOSHIBA
2SC1845 (E, F)	AF, Law noise	NPN Si-E	120	5	50	500	125	0.05 max.	120	300 ~ 800	6	7.0	0.3 max.	10	1	110	6	-1	2.5 max.	Complementary to 25A992	NEC
25C1941 (L, K)	AF, Oriver	NPN Si-E	160	5	50	800	150	0.1 max.	160	135	10	1	0.6 max.	20	2	170	10	-10	a max.		NEC
2SC2229 (O, Y)	AF, Driver	NPN Sr-Td	200	5	50	800	150	0.1 max.	200	70 ~ 240	5	10	0.5 max.	10	1	120	30	10-	5 max.		TOSHIBA
25C2235 (O, Y)	AF, Driver	NPN Si-E	120	5	800	900	150	T max.	120	80 ~ 240	5	100	max.	500	50	120	5	1001	30 max,		TOSHIBA
25C2240 (GR, BL)	AF, Low Noise	NPN Si-E	120	5	100	300	125	D.I max.	120	200 ~ 700	6	2	O.3 max.	10	1	100	6	1.	3		TOSHIBA
25C2275 IP, QI	AF. Power ams.	NPN Si-E	120	5	1.5A	25W (Tc = 25°C)	150	1 max.	120	100 ~ 320	5	300	2 max.	14	100	200	5	200°	19	Complementary to 25A985	NEC
25G2585 (O, A)	AF. Power amp.	NPN Si-E	160	5	15A	150W (Tc+25°C)	150	50 max.	160	55 ~ 150	5	1.4	2 max.	5.A	500	08	10	14*	200	Complementary to 2SA1095	TOSHIBA
25C2704 (O, Y)	AF. Driver	NPN SHE	150	5	50	10W (Tc+25°C)	150	0.1 max.	150	50 ~ 240	5	10	f max.	10	1	200	5	10*	8.1	Complementary to 2SA1144	TOSHIBA
250882 (P, Q)	AF, Power amp.	NPN S-E	40	5	34	1w	150	max.	30	100 ~ 320	2	20	0.5 max.	2A	200	90	5	- 100	45	Complementary to 258772	NEC

FIELD EFFECT TRANSISTOR

				UM RA				n Values edi			ELEC	TRIC	AL CHARA	CTER	ISTICS Tye	pical V	/alues: [T _A	* 25°	C unless as	(Between	e specified)				
DEVICE	APPLICA-	STRUC-	Orain	Source	Current			Channel Temper- ature	Gate Le Curren		Gate to D Breakdo Voltab	wn	Drain Cu	rent	Gate to So Cutoff Vo		Forward Tr Admitta		Feed Ba Capacita		Power G (Common S		Noise Fig	jure	MANU- FACTURES
:			V500	VGSG	lg (mA)	Io (mA)	PD ImWi	T _{ch}	Test Conditions	IGSS (nA)	Test Conditions	Vigar GDO (V)	Test Conditions	(Am)	Test Conditions	VGS WITH	Test Conditions	(Mg)	Test Conditions	Crss to#1	T#st Conditions	(48)	Test Conditions	NF (dB)	
25K150 A (GR)	AF, Low hoise Differential amp.	Si N-channel junction (Dual)	- 50	- 50	10		200 ·	125	VG5- -30v VDS-0	-1 max.			V65=10V VGS=0	2.£ ~6.5			Vos=10V Vos=0 f=1 kHz loss=	12	V _{DG} =10V {D=0 {=1 MHz	3			Vos=10V Pg=1 kfl lo=1 mA f=1 kHz	2	TCSHIEA

DIODES, LED'S

								oiute - Ma therwise s		alues:			ELE	CTRICA	L CHARA	CTERIS'	TICS Typics rise specified	i Values:	
DEVICE			Pieverse		Reverse	Peax	Peak	Average			Total	Forwar	re Current	Forwe	ra Voltage	Rever	se Current	Others	MANU-
TYPE	APPLICATIONS	STRUCTURE	Surge Voltage	Reverse Voltage	Voitage		Current	Restitied Current	Surge Current	Temperature	Power Dissipation	lemin	Test Concition	V≠mas	Test Condition	Rmax	Condition	Q.mers	FACTURER
			Visurge (V)	VRM	Ve (V)	VFM (V)	lem (mA)	10 (m4)	1F surge (A)	T _a	PD (mW)	(mA)	VF (V1	ivi	iF (mA)	luAJ	VR (V)		
2-0.490	Detector	Ge-Pc			15		150		0.4	75		4	1						MATSUSHITA
152076	Medium speed Switching	Si-EP		35	30		450	150	1	175	250			0.8	10	1	30		нітасні
	Medium speed Switching	\$1-27		70	60		450	150	1	175	250			0.8	10	1	30		HITACHI
GP10 -4002	Rectifier	Si-DJ		100	70			1A	30	175				1,1	14	5			GENERAL INSTRUMENT
wo2	Rectifier	Si-OJ (Bridge)			200	200		1.5A	50	125				1.0	1A	10		Pan = 50°C/W	GENERAL INSTRUMENT
S10VB20	Rectifier	Si-OJ (Bridge)		200				10A	200	150				1.05		10			SHINDENGEN
eP55045	Lamp (red)	GaAIAs			4		300	ls = 50		85	100			2.0	20	100	4	ly = 80 med (le = 20 mA)	STANLEY
PR5527\$	Lamp (red)	GaP			. 4		100	1F - 30	-	85	75			2.0	10	100	4	ly = 1.2 mcd ([F = 10 mA)	STANLEY

ZENER DIODES

				(IMUM RATI te - Maximum uniess otherw	Values:			EL	ECTRICAL	CHAR	ACTERI	STICS Typ	ical Val	ies: IT,	a = 25°C ur	niess och	nerwise spec	rfied)	
TYPE	APPLICATIONS	STRUCTURE	Total Power Dissipation	Zener Current	Junction Temperature		Zener Vz	Voltage	Test Conditions	Differ		Test Conditions	Tempe		Test Conditions		Test Conditions	Others	MANU- FACTURER
			PO (mW)	IZ (A)	T ₃	MIN (v)	TYP	MAX (V)	1z (mA)	TYP (Ω)	MAX	lz	TYP	NAX N O	1z (mA)	MAX (µA)	Va (v)		
8013E33	Regulator	Zi-J	£00		175	12.99		13.66	10		25	10				2	10		NEC
RD22ES4	Regulator	51	400		175	21.52		22.63	5		60	5				2	17		NEC

ITEGRATED CIRCUITS AN6552

Manufacturer: MATSUSHITA

Applications: Dual Operational Amplifier

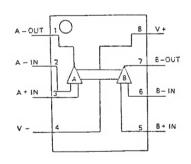
BSOLUTE MAXIMUM RATINGS

Supply Voltage	Input Voltage
Internal Power Dissipation 500 mW	Storage Temperature Range40°C to +125°C
Differential Input Voltage ±30 V	Operating Temperature Range20°C to +75°C

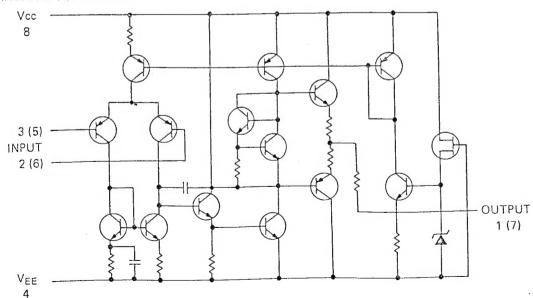
LECTRICAL CHARACTERISTICS (VCC = ±15V, TA = +25°C unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	$R_S \le 10 \text{ k}\Omega$		0.5	6.0	mV
Input Offset Current			5	200	nA
Input Bias Current				500	nA
Large-Signal Voltage Gain	$R_L \ge 2 k\Omega$ $V_{out} = \pm 10 V$	86	100		dB
Output Voltage Swing	$R_L \ge 2 k\Omega$	±10	±13		V
Common Mode Rejection Ratio	$R_S \le 10 \text{ k}\Omega$	70	90		dB
Supply Voltage Rejection Ratio	$R_S \le 10 \mathrm{k}\Omega$		30	150	μ\/\
Slew Rate	R _L ≥ 2 kΩ		1		V/μS

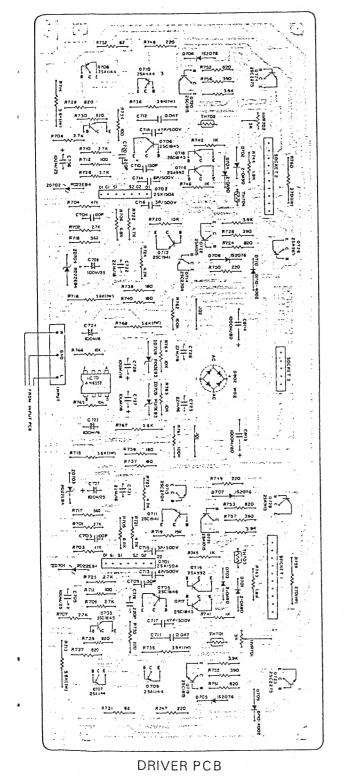
ERMINAL GUIDE (TOP VIEW)

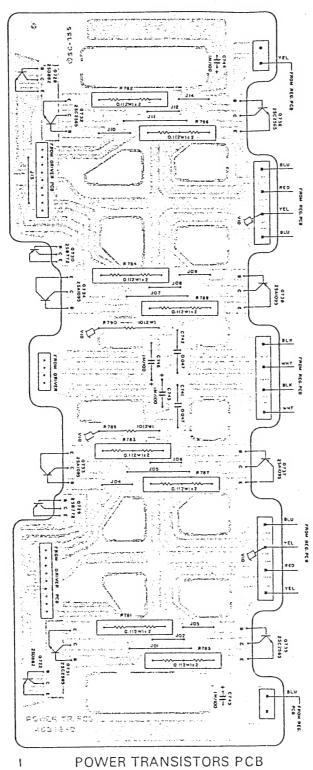


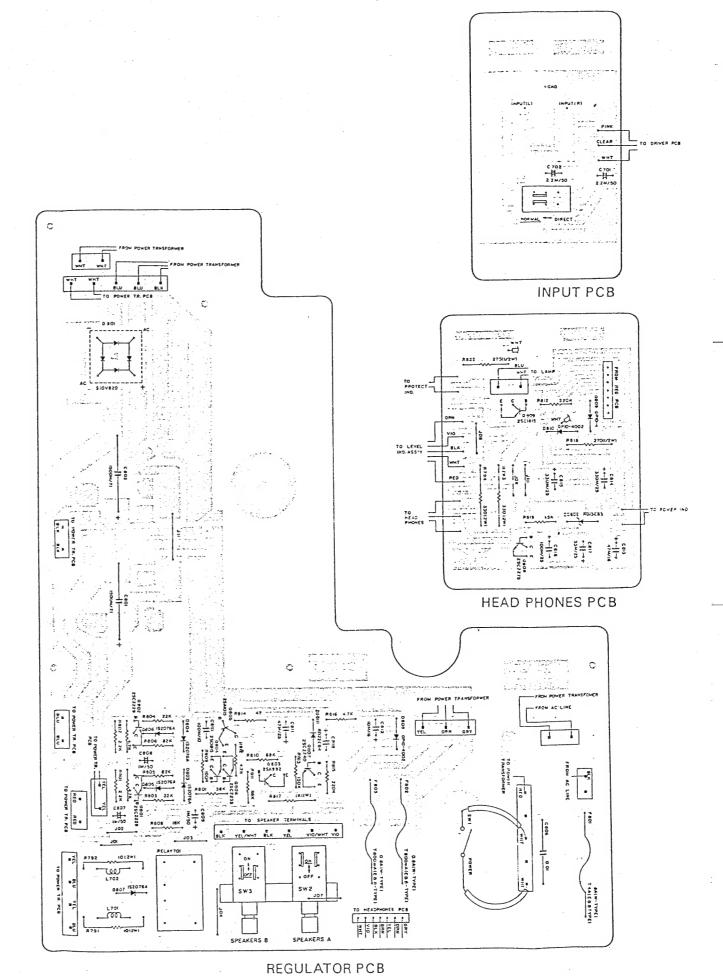
SCHEMATIC DIAGRAM (1/2 CIRCUIT)



P. C. BOARD (BOTTOM VIEW) Figure 7







SCHEMATIC DIAGRAM

K * 1,000; M * 1,000,000

3. CAPACITANCE VALUES 1.0 AND ABOVE ARE IN pF OR pF (P * pF, M * pF), LESS THAN 1.0 ARE IN pF, LELECTROLYTH CAPACITANCE VALUES ARE IN pF, WV.)

4. VOLTAGES ARE MEASURED TO CHASSIS GROUND WITH A "DC VOLTMETER".

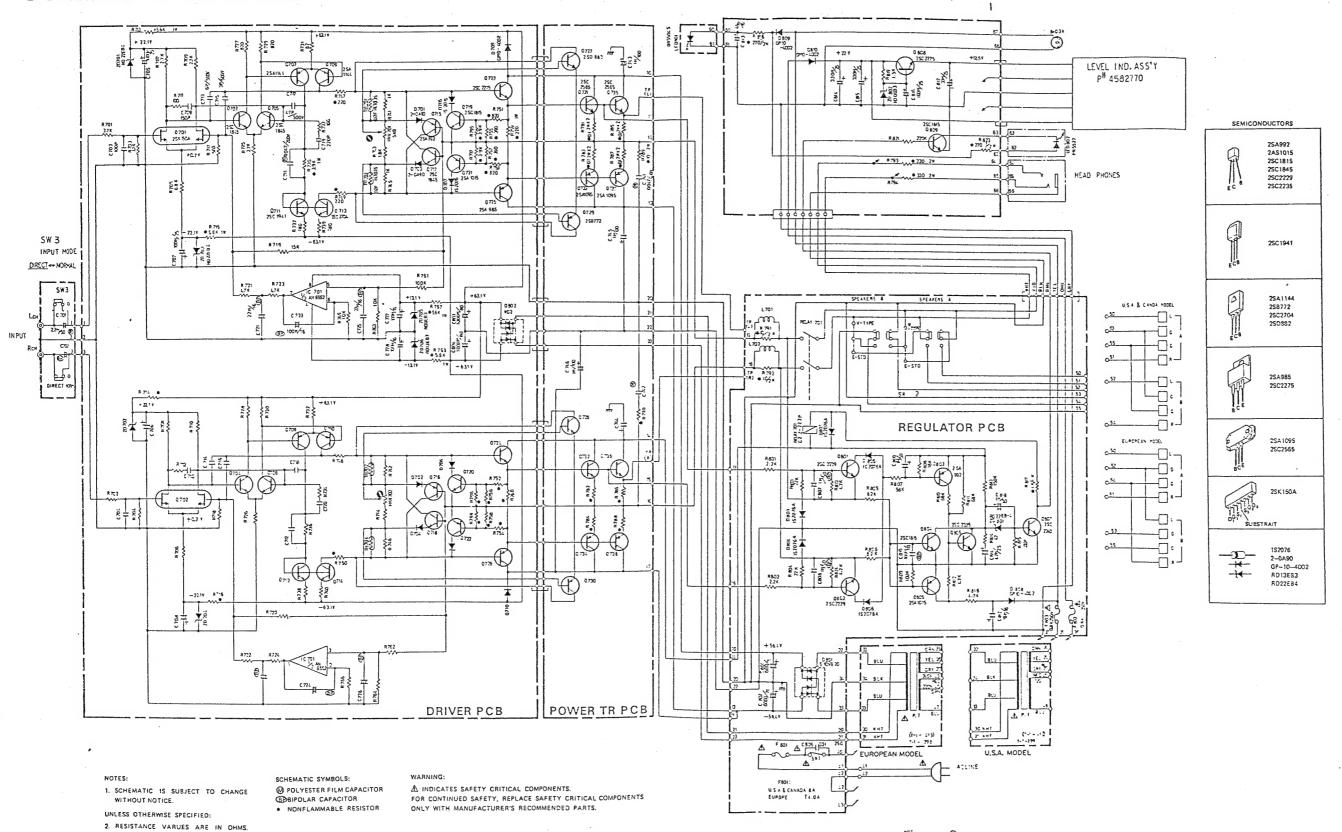


Figure 6